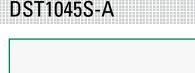
Schottky Barrier Rectifier DST1045S-A, 10A, 45V, TO-277B, Single

AUTOMOTIVE GRADE HF RoHS

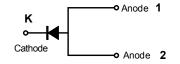


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Expertise Applied | Answers Delivered



Pin out



Description

Littelfuse DST series Ultra Low VF Schottky Barrier Rectifier is designed to meet the general requirements of automotive applications by providing high temperature, low leakage and low VF products.

It is suitable for high frequency switching mode power supply applications, as free-wheeling and polarity protection diodes.

Features

- Ultra low forward voltage drop
- High frequency operation
- High junction temperature capability
- Hi reliability application and automotive grade AEC-Q101 qualified
- Trench MOS Barrier Schottky technology
- Single die in TO-277B Package

Applications

- Switching mode power
- Free-Wheeling diodes
- supply
- DC/DC converters
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V _{RWM}	-	45	V
Average Forward Current *	I _{F(AV)}	50% duty cycle @T _L = 125 °C rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	150	А

* Mounted on 30 mm x 30 mm pad areas aluminum PCB

Electrical Characteristics

Parameters	Symbol	Test Conditions	Тур	Max	Unit
Forward Voltage Drop *		@5A, Pulse, T _J = 25 °C	0.43	0.51	- V
	V _{F1}	@10A, Pulse, T _J = 25 °C	0.49	0.57	
		@5A, Pulse, T _J = 125 °C	0.32	0.43	
	V _{F2}	@10A, Pulse, T _J = 125 °C	0.41	0.50	
Reverse Current *	I _{R1}	$@V_{R} = rated V_{R} T_{J} = 25 \text{ °C}$	0.003	0.019	m۸
neverse cullent "	I _{R2}	$@V_{R} = rated V_{R} T_{J} = 125 \text{ °C}$	5	15	mA
Junction Capacitance	C _T	$@V_{R} = 5V, T_{C} = 25 \text{ °C}, f_{SIG} = 1MHz$	656	-	pF

* Pulse Width < 300µs, Duty Cycle <2%

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Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	TJ		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Thermal Resistance Junction to Ambient	R _{eja}	DC operation	75	°C/W
Typical Thermal Resistance Junction to Lead	R _{eJL} *	DC operation	3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style	ТО-277В			

(1) Free air, mounted on recommended copper pad area; thermal resistance $R_{\Theta^{JA}}$ - junction to ambient (2) Mounted on 30 mm x 30 mm pad areas aluminum PCB; thermal resistance $R_{\Theta^{JI}}$ - junction to lead

*Lead temperature monitored at the cathode pin

Figure 1: Forward Current Derating Curve

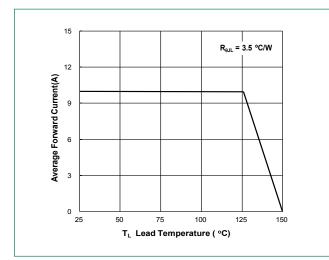


Figure 3: Typical Instantaneous Forward Voltage Characteristics

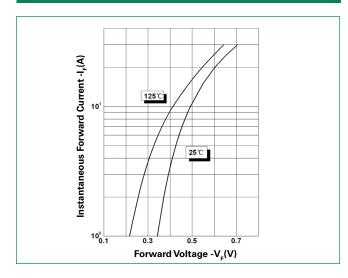


Figure 2: Forward Power Loss Characteristics

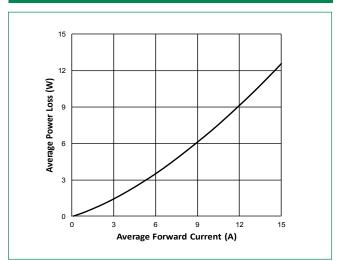
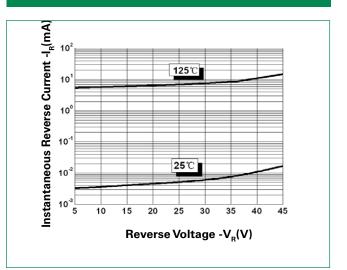


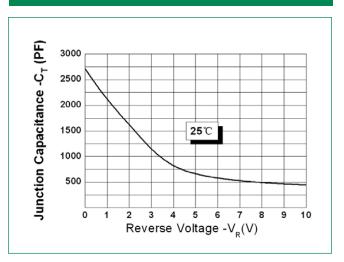
Figure 4: Typical Reverse Characteristics



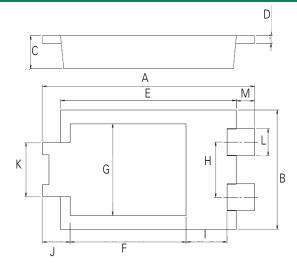


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Figure 5: Typical Junction Capacitance

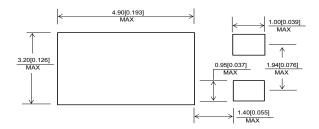


Dimensions-TO-277B



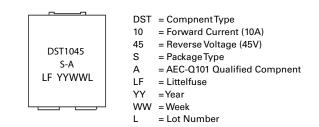


Mounting Pad Layout



Symbol	Millimeters			
	Min	Тур	Max	
Α	6.30	6.50	6.70	
В	3.88	3.98	4.08	
С	0.95	1.10	1.25	
D	0.20	0.25	0.30	
E	5.28	5.38	5.48	
F	3.40	3.55	3.70	
G	2.90	3.05	3.20	
н	1.74	1.84	1.94	
I	1.10	1.25	1.40	
J	-	0.85	-	
К	1.70	1.80	1.90	
L	0.85	0.90	0.95	
М	-	0.56	-	

Part Numbering and Marking System



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